



Part number scheme  
**TO-94 A 85 N 16 STD**  
 1 2 3 4 5 6

- 1) Package designation
- 2) Anode to tread
- 3) Series number
- 4) Designates standard recovery time
- 5) Voltage Multiplier (example: 16 x 100 = 1600)
- 6) Specifies 1/2 - 20 UNF-2A Tread

### Features:

- ✓ All diffused silicone.
- ✓ Amplifying gate.
- ✓ Standard recovery time for phase control applications.
- ✓ Vibration resistant.
- ✓ Metal and ceramic package construction.

### Voltage

Parameter	Symbol	Rating	Units
Maximum Repetitive Off-State Voltage <small>Notes: 1, 3, 4, 5, 6, 7</small>	$V_{DRM}$	1600 ~ 2400	Volts
Maximum Repetitive Reverse Voltage <small>Notes: 1, 3, 4, 5, 6</small>	$V_{RRM}$	1600 ~ 2400	Volts
Maximum non repetitive Surge of Reverse Voltage <small>Notes: 2, 3, 4, 5, 6</small>	$V_{RSM}$	$V_{RRM} + 100$	Volts
Maximum non repetitive on-state Voltage drop <small>Notes: 2, 3</small>	$V_{TM} @ I_{TM}$	1.8 @ 250	V @ A
Critical rate of rising off-state Voltage, Linear to 80% of $V_{DRM}$ <small>Note: 2</small>	$dv/dt$	500	V/ $\mu$ s
<small>Note 1: <math>T_J</math> 25°C. Note 2: <math>T_J</math> 125°C. Note 3: Measured at the peak of the sine wave, Note 4: Below 0°C derate <math>V_{DRM}</math> and <math>V_{RRM}</math> 10%.            Note 5: <math>V_{DRM}</math> and <math>V_{RRM}</math> have <math>I_{DRM}</math>, <math>I_{RRM}</math> of up to 35mA. Note 6: <math>V_{DR}</math> and <math>V_{RR}</math> have typical <math>I_{DR}</math>, <math>I_{RR}</math> of 2-7mA. Note 7: For DC applications derate <math>V_{DRM}</math> 45%.</small>			
<small>Specifying voltage: 1800V, TO-94A85N18 2200V, TO-94A85N22            1600V, TO-94A85N16 2000V, TO-94A85N20 2400V, TO-94A85N24 Above 2400V inquire for availability.</small>			

### Gate

Parameter	Symbol	Rating			Units
		Temp.	Typ.	Max.	
Gate Trigger Voltage <small>Note 3</small>	$V_{GT}$	-20°C	1.9 ~ 2.2	3	Volts
		25°C	1.4 ~ 1.6		
		125°C	1.9 ~ 2.3		
Maximum Gate Trigger Current <small>Notes 1,3</small>	$I_{GT}$	150			mA
Minimum Forward Current to Latch on-state <small>Notes 1, 5</small>	$I_L$	300			mA
Minimum Forward Current to Hold on-state <small>Notes 1, 5</small>	$I_H$	300			mA
Average Gate Power (recommended) <small>Note 2, 3</small>	$P_{G(AVE)}$	0.9 ~ 2			Watts
<small>Note 1: <math>T_J</math> 25°C. Note 2: <math>T_J</math> 125°C. Note 3: Rectangular pulse, <math>t_p \leq 8.3</math> ms. Note 4: Rectangular -<math>V_{DC}</math> pulse, <math>t_p \leq 8.3</math> ms. Note 5: Test conditions: <math>I_{DC}</math>, <math>R_L = 12\Omega</math>.</small>					

### Current

Parameter	Symbol	Rating	Units
Maximum, Average, On state, Current <small>Notes: 3, 4</small>	$I_{T(AVE)}$	85	Amperes
Maximum, RMS, On state, Current <small>Notes: 3, 5</small>	$I_{T(RMS)}$	136	Amperes
Maximum non repetitive, Surge, On state, Current, with no reverse voltage reapplied. <small>Notes: 2, 4</small>	$I_{TSM} 0\% V_{RRM}$	1.7	kA
Critical rate of rising On-state Current, non repetitive <small>Note: 6, 7</small>	$di/dt$	150	A/ $\mu$ s
$I_{DRM}$ = Maximum (threshold), Repetitive, Off-State, Current. <small>Note: 1</small> $I_{RRM}$ = Maximum (threshold), Repetitive, Reverse, Current. <small>Note: 1</small>	$I_{DRM}$ & $I_{RRM}$	10	mA
Fuse's absolute maximum $I^2 t$ with no reverse voltage reapplied <small>Note: 2, 4</small>	$I^2 t, 0\% V_{RR}$	32.5	kA
<small>Note 1: <math>T_J</math> 25°C. Note 2: <math>T_J</math> 125°C. Note 3: <math>T_{Case}</math> 85°C, air cooled. Note 4: 180° conduction, 60Hz sine wave.            Note 5: Test conditions: <math>I_{DC}</math>, <math>R_L = 12\Omega</math>. Note 6: Switching from <math>V_{DRM} \leq 1000V</math> Note 7: In addition to 0.2<math>\mu</math>F and 20<math>\Omega</math> snubber circuit</small>			

### Thermal & Mechanical

Parameter	Symbol	Rating	Units
Operating Temperature Range	$T_J$	-40° ~ 125°	°Celsius
Maximum Thermal resistance, Junction to Case	$R_{th-J-C}$	0.30	°C/W
Maximum Thermal resistance, Case to Heat Sink	$R_{th-C-HS}$	0.13	°C/W
<b>Mounting Torque</b>		15.5 (14.0)	Nm
<small>Non Lubricated Treads (Lubricated Treads)</small>		137 (120)	lbf-in